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Docket No. P1296

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT(S):

BIN YU

SERIAL NO.:

09/826,472

EXAMINER: RON E. POMPEY

FILED:

APRIL 4, 2001

ART UNIT: 2812

FOR:

METHOD OF FABRICATING A SEMICONDUCTOR DEVICE HAVING A NITRIDE/HIGH-K/NITRIDE GATE DIELECTRIC STACK

BY ATOMIC LAYER DEPOSITION (ALD) (as amended)

BOX AF COMMISSIONER FOR PATENTS WASHINGTON, DC 20231

AMENDMENT AFTER FINAL REJECTION UNDER 37 C.F.R. § 1.116

To the Commissioner:

This letter is a Response to the final Office Action dated January 28, 2003. The Applicant hereby respectfully requests favorable consideration of the below-submitted amendment after final rejection, submitted under 37 C.F.R. § 1.116, and remarks.